Spin reorientation and crystal-field interaction in TbFe_{12-x}Ti_x single crystals

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The magnetic properties of $\text{TbFe}_{12-x}\text{Ti}_x$ single crystals with x=0.8-1.4 have been investigated in detail using ac and dc susceptibility and high-field magnetization measurements. A first-order spin reorientation transition from a basal plane easy magnetization direction at low temperatures to an axial easy magnetization direction at high temperatures occurs for all the investigated compounds. The spin reorientation temperatures have been determined by combining ac and dc susceptibility measurements and its dependence on both the Ti content and the applied magnetic field has been studied. A first-order magnetization process is observed below a certain temperature when the magnetic field is applied along the [001] crystallographic direction. The dependence of the transition critical field on the Ti content has been analyzed. The magnetic behavior has been interpreted using a two-sublattices model for the magnetic structure, in the frame of a crystal-electric-field-mean-field model. The parameters describing the crystal-field interaction in TbFe $_{12-x}$ Ti $_x$ compounds have been determined. The calculated magnetic behavior shows a good agreement with experimental results in a wide temperature range.

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I. INTRODUCTION

In recent years, many studies have been undertaken to improve the magnetic properties of iron-based rare-earth (R)transition-metal (T) intermetallic compounds. In particular, great attention has been paid to the ThMn₁₂-type R-T compounds due to their magnetic properties and simple crystal structure.² From a fundamental point of view, this series provides a good opportunity to study the crystal-field interaction in R-T intermetallic compounds. These compounds have a tetragonal structure (space group I4/mmm) with only one Rsite (2a) and three nonequivalent T sites (8i, 8j, and 8f). Several attempts have been made in order to explain the magnetic properties of these intermetallics from a microscopic point of view.³⁻⁹ Of particular interest is the knowledge of the anisotropy arising from the rare-earth sublattice, which has its origin in the crystal-electric-field (CEF) interaction. The R-sublattice contribution to the magnetic anisotropy energy can be described in the frame of a single-ion CEF model, where the CEF interaction is described by the so-called CEF Hamiltonian, in which the CEF parameters B_n^m account for the intensity of such interaction.⁸ The CEF parameters set can be determined by fitting different experimental results to the CEF model, such as magnetization measurements and inelastic neutron scattering. Moreover, the occurrence of the field- or temperature-induced magnetic transitions like spin reorientation transitions (SRT's) or firstorder magnetization processes (FOMP's) can impose strong limitations on the values of the CEF parameters. 10,11 In the case of the RFe₁₁Ti compounds there are some discrepancies with respect to the number and value of the CEF parameters necessary to describe the R anisotropy.^{3,4,9} For example Hu et al. have obtained a set of five CEF parameters by fitting the experimental magnetization data of DyFe₁₁Ti single crystal, but they cannot account for the magnetic behavior of TbFe₁₁Ti compound.³

Considerable confusion also exists about the magnetic structures occurring in the RFe₁₁Ti compounds at various temperatures and about the nature of the magnetic phase transitions. In particular for TbFe₁₁Ti, very large discrepancies do exist with regard to the spin reorientation transition. 12-14 In a previous work these differences were ascribed to the fact that the temperature and character of the SRT are very sensitive to the applied magnetic field. 15 Rather fewer investigations of the composition influence on magnetic properties in RFe_{12-x}Ti_x compounds have been reported. Generally speaking, the Curie temperature T_C is very sensitive to the composition in the R-T compounds, and can be regarded as a parameter to compare the possible differences in composition. However, our recent investigation on RFe_{12-x}Nb_x compounds clearly indicated that a slight change of the Nb concentration in DyFe_{12-x}Nb_x and TbFe_{12-x}Nb_x compounds can lead to a pronounced shift of the spin reorientation temperature even though T_C keeps almost constant. 16 Therefore, in order to explain the discrepancies reported in the literature about spin reorientation transition in TbFe₁₁Ti, it is necessary to further investigate, in TbFe_{12-x}Ti_x compounds, the influence of the chemical composition and/or other external conditions on the anisotropy. Compared to polycrystalline samples, single-crystalline samples enable a more precise observation of magnetic transitions and provide more accurate information from the magnetic measurements. It is well known that the ac susceptibility depends on the magnetic anisotropy. Therefore, the measurement of the temperature dependence of the complex susceptibility, $\chi_{ac} = \chi' - j\chi''$ can be used to detect the temperature-induced magnetic transitions caused by the change of the magnetic anisotropy energy in the R-T compounds. 17

In this paper, a detailed investigation of spin reorientation transitions and first-order field-induced transitions in various TbFe $_{12-x}$ Ti $_x$ single crystals using ac and dc susceptibility measurements and high-field magnetization measurements is presented. Moreover, the magnetic behavior of some TbFe $_{12-x}$ Ti $_x$ compounds is analyzed from a microscopic point of view in a wide temperature range using a single-ion exchange and CEF interaction model, which constitutes a very strict test of validity of the model used and also guarantees the reliability of the determined parameters.

II. EXPERIMENTAL METHODS

The magnetization and ac susceptibility have been measured on TbFe_{12-x}Ti_x single-crystalline samples with x=0.8-1.4. The samples were grown by the Czochralski technique with a cold crucible, and cut in the Institute of Physics, Chinese Academy of Science. Details of the preparation and quality of the single crystals can be found in Ref. 18. High-field magnetization measurements were performed in the Van der Waals-Zeeman Institute, University of Amsterdam. The $YFe_{12-x}Ti_x$ polycrystals have been prepared by argon arc melting the constituent elements with purities of at least 99.9%. The ingots were wrapped in molybdenum foil and sealed in quartz tubes, followed by annealing in vacuum at 1273 K for 72 h, and then quenched in water. In order to obtain magnetically aligned samples, fine-powdered particles of the YFe_{12-x}Ti_x compounds were mixed with epoxy resin and filled in two plastic tubes of cylindrical shape. The plastic tubes were placed in an external magnetic field of about 1.0 T with their cylindrical axis either parallel or perpendicular to the field direction, respectively, until the epoxy resin solidifies. The ac susceptibility measurements were performed in a superconducting quantum interference device with an ac field of 4.5 Oe and frequencies of 10 and 100 Hz. In the present investigation, various dc fields have been applied.

III. EXPERIMENTAL RESULTS

Both x-ray-diffraction measurements and thermomagnetic analysis show that all TbFe_{12-x}Ti_x single crystals and $YFe_{12-x}Ti_x$ polycrystals are single phase, and crystallize in a ThMn₁₂-type structure. As an example, the M(T) curves obtained for some selected TbFe_{12-x}Ti_x single crystals under a low magnetic field applied along the [001] crystallographic direction are shown in Fig. 1. It can be seen that T_C presents an almost composition-independent value (554 K), while the spin reorientation temperature $T_{\rm sr}$ rapidly increases with decreasing Ti content. The composition dependence of $T_{\rm sr}$ and T_C in TbFe_{12-x}Ti_x is similar to the measured on $DyFe_{12-x}Nb_x$ and $TbFe_{12-x}Nb_x$ polycrystals.¹⁶ It can be observed that the decreasing rate of $T_{\rm sr}$ with increasing Ti content is larger than 300 K/Ti. This fact could explain the contradictory reports on the $T_{\rm sr}$ values for TbFe₁₁Ti in previous references, which may result from possible differences in chemical composition of the samples except for the case of

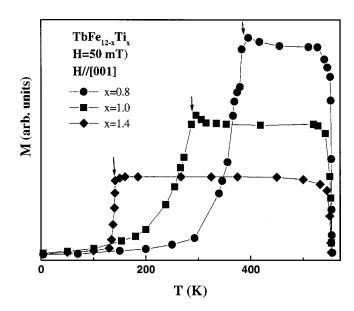


FIG. 1. Temperature dependence of the magnetization measured on TbFe_{1-x}Ti_x single crystals when the field is applied along the [001] crystallographic direction. $T_{\rm sr}$ is marked by arrows.

the field influence described in Ref. 12.

Figures 2(a) and 2(b) show the temperature dependence of the real (χ') and imaginary (χ'') components of the ac susceptibility of $TbFe_{10.7}Ti_{1.3}$ when the ac (\mathbf{h}_{ac}) and dc (\mathbf{H}) fields are applied parallel [Fig. 2(a)] or perpendicular [Fig. 2(b)] to the [001] direction, for several values of the dc field. For highly anisotropic materials, the value of χ' is determined mainly by the magnetic anisotropy energy and the domain-wall energy, whereas the value of χ'' gives the energy absorption by the compound. It can be seen that a pronounced anomaly occurs in both χ' -T and χ'' -T curves at about 200 K at zero dc field. In this case, when \mathbf{h}_{ac} is applied along the [001] direction the shape of the anomaly in both χ' and χ'' curves is steplike, whereas when the \mathbf{h}_{ac} field is perpendicular to [001] the anomaly becomes peaklike. According to magnetization measurements performed on single crystals when an external field is applied along different crystallographic directions at different temperatures, it can be concluded that the anomaly in both χ' and χ'' , as well as the one observed in the M(T) measurements, is due to a spin reorientation transition, in which the easy magnetization direction (EMD) changes from the basal plane ($T < T_{sr}$) to the c axis $(T>T_{\rm sr})$. In the literature the experimental definition of $T_{\rm sr}$ from the $\chi'(T)$ curves is somewhat controversial. Some authors assign $T_{\rm sr}$ to the inflection point (i.e., a minimum of $d\chi'/dT$), $^{9,19,20}_{}$ while other authors place $T_{\rm sr}$ at the χ' vs T maximum. 7,21,22 Here we have adopted the latest definition. Therefore $T_{\rm sr}$ for TbFe_{10.7}Ti_{1.3} is determined to be 205 K (±5 K). Under a nonzero applied dc field, the values of both χ' and χ'' rapidly decrease and the shape of the anomaly in both $\chi'(T)$ and $\chi''(T)$ becomes peaklike even for the curves obtained with \mathbf{h}_{ac} parallel to [001] [see Fig. 2(a)]. The position of the peak in both χ' and χ'' shifts to lower temperatures when H is applied along the [001] direction and to higher temperatures when H is applied perpendicular to the [001] direction. This effect means that although

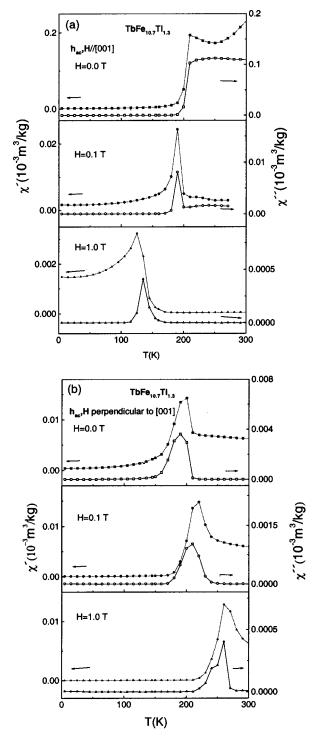


FIG. 2. Temperature dependence of the real, χ' , and imaginary (χ'') components of the ac susceptibility, when \mathbf{h}_{ac} and \mathbf{H} are applied parallel (a) or perpendicular (b) to the [001] direction in a TbFe_{10.7}Ti_{1.3} single crystal, for several values of H. (h_{ac} =4.5 Oe and f=100 Hz)

the Zeeman energy produced by the applied external dc field keeps the magnetization parallel to the field direction, the application of an external dc field modifies $T_{\rm sr}$: it increases 75 K when the **H** is applied parallel to the [001] direction, whereas $T_{\rm sr}$ decreases 60 K when the **H** is applied perpendicular to the [001] direction. This implies that the anisot-

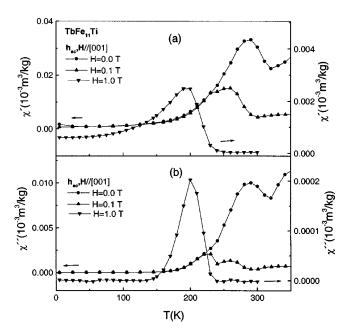


FIG. 3. Temperature dependence of the χ' (a) and χ'' (b) parts of the ac susceptibility for a TbFe₁₁Ti single crystal and values of \mathbf{h}_{ac} and \mathbf{H} . In all the cases $h_{ac} = 4.5$ Oe and f = 100 Hz.

ropy energy is comparable with the Zeeman energy produced by a 1.0-T applied magnetic field. As shown in Sec. IV this assumption will be confirmed by our CEF analysis.

The temperature dependence of χ' and χ'' in the case of the TbFe₁₁Ti single crystal when the \mathbf{h}_{ac} and \mathbf{H} are applied along the [001] direction, for several values of the dc field is shown in Figs. 3(a) and 3(b), respectively. The observed peaklike anomalies at H=0 indicate that a SRT occurs at about $T_{\rm sr}$ = 285 K, confirming the results obtained by Zhang et al. 14 According to magnetization measurements the EMD changes from an easy-plane EMD at low temperature to an easy-axis EMD at high temperature. Compared with TbFe_{10.7}Ti_{1.3}, the peak corresponding to the SRT anomaly in both $\chi'(T)$ and $\chi''(T)$ curves is more round in the present compound. When a dc field of 1.0 T is applied along the [001] direction $T_{\rm sr}$ decreases to 193 K (this decrease is larger than that for TbFe_{10.7}Ti_{1.3}). This dependence of $T_{\rm sr}$ on the value and direction of the applied magnetic field can be the origin of the very large discrepancies with regard to the type of spin reorientation and the value of $T_{\rm sr}$ reported for TbFe₁₁Ti compound mentioned in Sec. I (see Ref. 15 for a summary). In the M(T) curves a similar tendency for the variation of $T_{\rm sr}$ under applied field has been observed in single crystal¹⁵ and in polycrystalline samples.⁹

Figures 4(a) and 4(b) display the results for $\chi'(T)$ and $\chi''(T)$, respectively, obtained on a TbFe_{11.15}Ti_{0.85} single crystal with the ac field applied along the [001] direction in various dc fields. $T_{\rm sr}$ is derived to be 340 K at zero dc field. With an increasing dc field the shape of both $\chi'(T)$ and $\chi''(T)$ curves becomes much sharper. A 1.0-T dc field applied along the [001] direction shifts $T_{\rm sr}$ to 238 K. The effect of the ac frequency changes from 100 to 10 Hz on $T_{\rm sr}$ has also been studied, but no influence on either $\chi'(T)$ or $\chi''(T)$ curves has been observed.

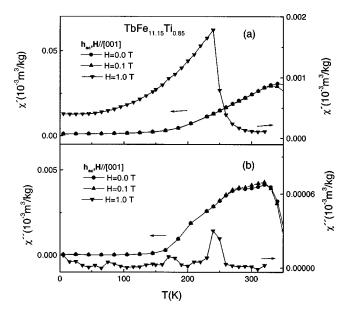


FIG. 4. Temperature dependence of the χ' (a) and χ'' (b) parts of the ac susceptibility for a TbFe_{11.15}Ti_{0.85} single crystal in various dc fields. ($h_{\rm ac}$ =4.5 Oe and f=100 Hz).

The magnetization isotherms, obtained when the field is applied along the [001] direction for TbFe_{10.7}Ti_{1.3}, are shown in Fig. 5. A jump in the magnetization takes place below 210 K, being more evident at low temperatures (the magnetization value at 1.5 K changes from $5.5\mu_B/f.u.$ at 3.5 T to $10.4\mu_B/f.u.$ at 4.2 T). This particular field dependence of the magnetization and its similarity with the observed in

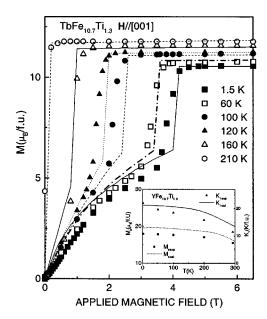


FIG. 5. Magnetization isotherms of TbFe $_{10.7}$ Ti $_{1.3}$ when the magnetic field is applied along the [001] direction. The symbols correspond to the experimental data and the lines represent the calculation for the parameters set collected in Table I. Inset: temperature variation of the iron anisotropy constant K_1 and the iron magnetization M_s . Symbols are the experimental values obtained from the YFe $_{10.7}$ Ti $_{1.3}$ polycrystal. Lines are the theoretical calculation using the parameters listed in Table I.

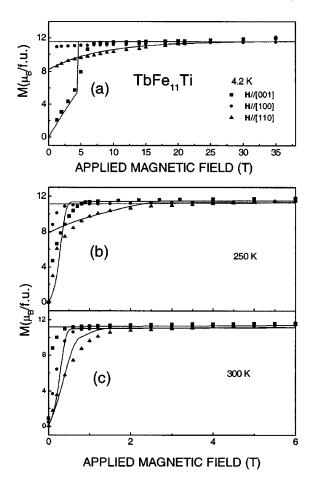


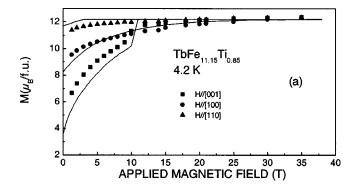
FIG. 6. Magnetization isotherms of TbFe₁₁Ti obtained when the magnetic field is applied along the crystallographic axes [100], [110], and [001]. Full lines are the theoretical curves obtained using the parameters listed in Table I.

other ThMn₁₂ compounds,^{4,9} points to the existence of a FOMP-like transition. It can also be seen that the critical field at which this transition takes place decreases with increasing temperature.

The magnetization isotherms obtained for TbFe₁₁Ti and TbFe_{11.15}Ti_{0.85} under an applied field along the different crystallographic directions at some selected temperatures are shown in Figs. 6 and 7, respectively. It can be seen that the transition critical field at 4.2 K shifts from 3.5 T for x = 1.3 to 4.4 T for x = 1.0, and to 10.0 T for x = 0.85.

IV. ANALYSIS

To interpret the observed behavior we will work in the frame of an ionic CEF model. In order to account for the total free energy of a compound we will consider two main contributions: the R-sublattice contribution and the Fesublattice one. The R-sublattice contribution can be calculated from the Hamiltonian describing the magnetic properties of the R^{3+} ions in the tetragonal RFe $_{12-x}$ Ti $_x$ compounds in the presence of an internal magnetic field H_i . It can be written as



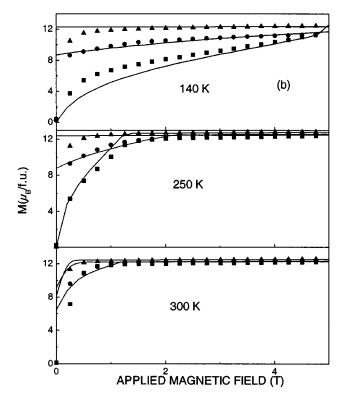


FIG. 7. Magnetization isotherms of TbFe $_{11.15}$ Ti $_{0.85}$ obtained when the magnetic field is applied along the crystallographic axes [100], [110], and [001]. Full lines are the theoretical curves obtained using the parameters listed in Table I.

$$H = H_{\text{CEF}} + 2(g_J - 1)\mu_B \boldsymbol{J} H_{\text{ex}}(T) + g_J \mu_B \boldsymbol{J} \boldsymbol{H}_i, \qquad (1)$$

where $H_{\rm CEF}$ represents the CEF Hamiltonian, which describes the CEF interaction at the rare earth site. As noted in Sec. I, a knowledge of this interaction is of fundamental importance for understanding the R-sublattice anisotropic behavior. The CEF Hamiltonian at the rare-earth 2a sites in the ThMn₁₂-type structure can be expressed as

$$H_{\text{CFF}} = B_2^0 O_{20} + B_4^0 O_{40} + B_4^4 O_{44} + B_6^0 O_{60} + B_6^4 O_{64}, \quad (2)$$

where the B_n^m are the CEF parameters and the O_{nm} are the CEF Stevens operators.⁸ The second term of Eq. (1) represents the 3d-4f exchange interaction, which can be expressed, within the mean-field approximation, by an effective exchange magnetic field $H_{ex}(T)$, considered proportional in magnitude and antiparallel to the iron sublattice magnetiza-

tion: $H_{\rm ex}(T) = H_{\rm ex}(0) [M_{\rm Fe}(T)/M_{\rm Fe}(0)]$. J is the R^{3+} total angular momentum and g_J the Landé factor. The last term of Eq. (1) describes the Zeeman interaction of the R^{3+} sublattice under an internal field H_i .

The magnetic free energy of the R^{3+} sublattice is obtained from the canonical partition function $Z_R = \sum_n \exp(-E_n/k_B T)$ where E_n are the eigenvalues of the Hamiltonian given by expression (1). The free energy of the rare-earth sublattice is given by

$$F^{R}(\theta, \varphi, \theta_{H}, \varphi_{H}, H_{i}, T) = -k_{R}T \ln Z_{R}, \qquad (3)$$

where H_i is the magnitude of the internal field, θ_H and φ_H are the spherical angles determining the direction of H_i , and θ and φ are the spherical angles for the exchange mean-field (H_{ex}) direction.

The total free energy is calculated by adding to F_R the uniaxial Fe sublattice anisotropy free energy together with the Zeeman interaction for the Fe sublattice, i.e.,

$$F(\theta, \varphi, \theta_H, \varphi_H, H_i, T)$$

$$= -k_B T \ln Z_R + K_1(T) \sin^2 \theta - M_{\text{Fe}}(T) H_i [\sin \theta \sin \theta_H$$

$$\times \cos(\varphi_H - \varphi) + \cos \theta \cos \theta_H], \tag{4}$$

where $M_{\rm Fe}(T)$ and $K_1(T)$ represent the thermal variation of the magnetization and anisotropy constant of the Fe sublattice, respectively, determined from the corresponding ${\rm YFe}_{12-x}{\rm Ti}_x$ compound and scaled to the Curie temperature of the corresponding ${\rm TbFe}_{12-x}{\rm Ti}_x$ compounds.^{3,9} The magnetic structure at any given temperature and applied magnetic field is determined by the exchange mean-field equilibrium angles θ_0 and φ_0 , which minimize the total free energy given by Eq. (4).

The process of determination of the CEF parameters from the magnetization results in the present work follows the procedure described in Ref. 10, taking into account the restrictive conditions imposed by the occurrence of a FOMPlike transition and of a SRT. For determining the CEF parameters we have proceeded as follows. First we consider an experimental magnetization isotherm $M_{\text{expt}}(T_1)$ obtained at low temperature T_1 (for example, $T_1 = 1.5 \text{ K}$ for TbFe_{10.7}Ti_{1.3}). Given a certain parameter set, if the calculated magnetization $M_{\rm cal}(T_1)$ lies for the measured field range within a reasonable error bar $M_{\rm expt}\pm\Delta M_{\rm expt}$, then the set is considered for further analysis. In this way we obtain several $\{B_n^m\}$ sets associated with temperature T_1 . In the following steps the number of possible solutions is reduced gradually by means of imposing the restrictions given by other highertemperature experimental isotherms $M_{\text{expt}}(T_2)$, $M_{\text{expt}}(T_3)$, etc. Due to the large number of parameters involved in the calculation we did not find a unique solution. Several sets of parameters give acceptable fits to all the experimental data. Among them we have considered the set which leads to the best fit of the experimental data. The CEF parameters determined by the fitting procedure for TbFe_{10.7}Ti_{1.3}, TbFe₁₁Ti, and TbFe_{11.15}Ti_{0.85} are listed in Table I. Due to the fact that for the TbFe_{10.7}Ti_{1.3} compound we could only analyze the magnetization isotherms along the [001] direction, the values

TABLE I. Crystal field B_n^m parameters (in units of K/ion), $\mu_B H_{\rm ex}(0)$ (in K units), at 0 K obtained from fitting the single-crystal magnetization curves of TbFe_{10.7}Ti_{1.3}, TbFe₁₁Ti, and TbFe_{11.15}Ti_{0.85}. A_n^m are the corresponding crystal-field coefficients (in units of Ka_0^{-n}): $A_n^m = B_n^m/\theta_n \langle r^n \rangle$, $\{\theta_n\}$ are the Stevens coefficients, and the $\langle r^n \rangle$ represent the Hartree-Fock radial intergrals.

TbFe _{10.7} Ti _{1.3}	B_{2}^{0}	B_4^0	B_4^4	B_6^0	B_6^4	$\mu_B H_{\rm ex}(0)$
	0.40 ± 0.02	$(-7.2\pm2)\times10^{-4}$	$(-90\pm10)\times10^{-4}$	$(-21\pm7)\times10^{-6}$	0	126
	A_2^0	A_4^{0}	A_4^4	A_6^0	A_6^4	
	-48 ± 2.5	-3.56 ± 1	-44 ± 5	2.73 ± 0.9	0	
TbFe ₁₁ Ti	B_2^0	B_4^0	B_4^4	B_6^0	B_6^4	$\mu_B H_{\rm ex}(0)$
	0.43 ± 0.02	$(-11\pm3)\times10^{-4}$	$(-140\pm15)\times10^{-4}$	$(-3.8\pm1.4)\times10^{-6}$	0	149.5
	A_2^0	A_4^{0}	A_4^4	A_6^0	A_{6}^{4}	
	-51.8 ± 2.4	-5.4 ± 1.5	-69.3 ± 7.5	0.49 ± 0.2	0	
$TbFe_{11.15}Ti_{0.85}$	B_2^0	B_4^0	B_{4}^{4}	B_6^0	B_6^4	$\mu_B H_{\rm ex}(0)$
	0.45 ± 0.02	$(7.3\pm2)\times10^{-4}$	$(130\pm15)\times10^{-4}$	$(-18\pm6)\times10^{-6}$	0	150.2
	A_2^0	A_4^{0}	A_4^4	A_6^0	A_6^4	
	-54.2 ± 2.4	3.61 ± 1	64.32 ± 7.4	2.34 ± 0.8	0	

of B_4^4 and B_6^4 for this compound have to be taken with certain reservations. The calculated M(H) curves for these compounds are drawn by solid lines in Figs. 5, 6, and 7. In all the cases it can be seen that the obtained parameters sets account quite well for the experimental results.

In the inset of Fig. 5, the thermal variation of the magnetization M_s at zero field and the anisotropy constant K_1 of YFe_{10.7}Ti_{1.3}, together with the curves used in the fitting for the Fe-sublattice contribution, are shown. The calculated spin reorientation temperature in absence of an external applied field is 215 K which agrees well with the data obtained from ac susceptibility measurement.

In the case of for TbFe₁₁Ti the magnetization isotherms shown in Fig. 6 show that the magnetic anisotropy within the (001) plane is very large, and that the magnetic field needed to saturate the magnetization along the [110] direction is larger than the one needed to saturate along the [001] direction. A similar behavior was observed in a DyFe₁₁Ti single crystal.³ In a phenomenological way the anisotropy of Tb³⁺ ion in these compounds can be described by the expression²³

$$E_{Tb}^{a} = K_{1}(Tb)\sin^{2}\theta + [K_{2}(Tb) + K_{2}'(Tb)\cos 4\phi]\sin^{4}\theta + [K_{3}(Tb) + K_{3}'(Tb)\cos 4\phi]\sin^{6}\theta,$$
 (5)

where θ and ϕ are the polar angles of the magnetization vector in a reference frame where \mathbf{x} is parallel to [100] and \mathbf{z} is parallel to [001]. The anisotropy energy between [110] and [100] in the basal plane can be written as

$$\Delta E = E_{[110]} - E_{[100]} = -2[K_2'(Tb) + K_3'(Tb)]. \tag{6}$$

The relationship between the anisotropy constants $\{K_i\}$ for the rare-earth and crystal-field parameters, $\{B_n^m\}$, can be obtained by a rotation transformation of crystal-field terms: 23,24

$$K_{1}(R) = -\left[\frac{3}{2}B_{20}\langle O_{20}\rangle + 5B_{40}\langle O_{40}\rangle + \frac{21}{2}B_{60}\langle O_{60}\rangle\right],$$

$$K_{2}(R) = \frac{7}{8}\left[5B_{40}\langle O_{40}\rangle + 27B_{60}\langle O_{60}\rangle\right],$$

$$K'_{2}(R) = \frac{1}{8}\left[B_{44}\langle O_{40}\rangle + 5B_{64}\langle O_{60}\rangle\right],$$

$$K_{3}(R) = -\frac{231}{16}B_{60}\langle O_{60}\rangle,$$

$$K'_{3}(R) = -\frac{11}{16}B_{64}\langle O_{60}\rangle.$$
(7)

The planar anisotropy is originated from the interplay of K_2' and K_3' which are determined by $B_4^4\langle O_{40}\rangle$ and $B_6^4\langle O_{60}\rangle$. The CEF parameters are related to the CEF coefficients A_n^m by the expression $B_n^m = \theta_n A_n^m \langle r^n \rangle$, where θ_n are the Stevens coefficients and $\langle r^n \rangle$ represent the Hartree-Fock radial integrals. According to Eq. (4), the larger planar anisotropy implies that A_4^4 and A_6^4 should take a rather large value compared with other two coefficients A_4^0 and A_6^0 . For TbFe₁₁Ti and TbFe_{11.15}Ti_{0.85}, one obtains $B_4^4\langle O_{40}\rangle = -83.1$ K, $B_6^4\langle O_{60}\rangle = -10.3$ K, and $B_4^4\langle O_{40}\rangle = 77.2$ K and $B_6^4\langle O_{60}\rangle = 18.3$, respectively. Since the values of $B_6^4\langle O_{60}\rangle$ are much smaller than those of $B_4^4\langle O_{40}\rangle$, the planar anisotropy is actually dominated by the $B_4^4\langle O_{40}\rangle$. This fact is also true for Hu and co-workers' CEF parameters. 3.24

It can be seen from Figs. 6 and 7 that at low temperatures the planar anisotropy changes dramatically when the Ti content increases from x = 0.85 to 1.0. At 5 K the EMD in the basal plane changes from [100] for x = 1.0 to [110] for x = 0.85 which is reflected from the change of the sign in B_4^4 , as shown in Table I. Because A_n^m are proportional to the electric field gradient (EFG) at the R sites, due to the nearestneighbor atoms at the 8i sites, substitution of Fe by Ti at

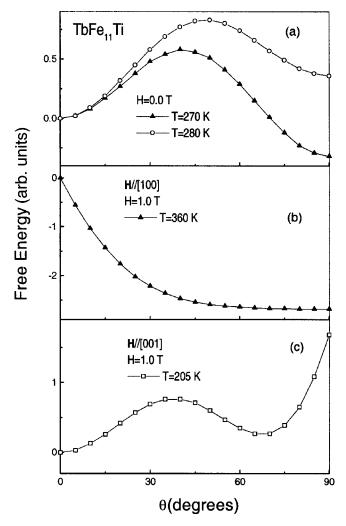


FIG. 8. Calculated free energy in the (100) plane for TbFe₁₁Ti for several orientations of the applied magnetic field. θ is the angle between the EMD and the [001] direction.

these sites causes a modification of the EFG. Therefore, it may be expected that, with increasing Ti content, A_4^4 may decrease and change its sign at a certain x, leading to the abovementioned change of the B_4^4 sign (for Tb, $\beta_J > 0$) and to the observed SRT within the (001) plane. The calculated $T_{\rm sr}$ using the CEF parameters listed in Table I are 270 and 320 K for TbFe₁₁Ti and TbFe_{11.15}Ti_{0.85}, respectively.

In order to study the influence of an applied magnetic field on the spin reorientation temperature, we have calculated the free energy in the (100) and (110) planes (φ_0 =0° and φ_0 =45°, respectively) at selected temperatures using the parameters set listed in Table I. As an example, the free energy in the (100) plane under various applied fields at the temperatures near $T_{\rm sr}$ is shown in Fig. 8 for the TbFe₁₁Ti compound. It can be seen that under zero field [Fig. 8(a)] the free energy minimum shifts from θ_0 =90° at 270 K to 0° at 280 K. This means that the EMD jumps from in the c plane at 270 K to along the c axis at 280 K. When a 1.0-T field is applied along the [100] direction the EMD still lies in the c plane even when temperature increases up to 360 K [see Fig.

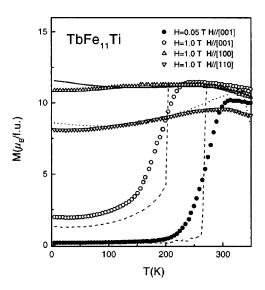


FIG. 9. Temperature dependence of the magnetization of $\text{TbFe}_{11}\text{Ti}$ for several applied magnetic fields. The symbols correspond to the experimental data and the lines represent the calculation for the parameters set listed in Table I.

8(b)]. Conversely, when such a field is applied along the [001] direction $T_{\rm sr}$ shifts to 205 K, as shown in Fig. 8(c). These theoretical predictions for the $T_{\rm sr}$ behavior account well for the experimental results displayed in Fig. 3.

We have also calculated the temperature dependence of the magnetization when the magnetic field is applied along different crystallographic directions, using the CEF parameters listed in Table I. As an example, the experimental and calculated results for TbFe₁₁Ti are shown in Fig. 9. The good agreement between the experimental and calculated data confirms the reliability of the obtained parameters. This is also the case of the other two compounds.

V. CONCLUSIONS

In the present paper, a detailed study of the magnetic properties of TbFe_{12-x}Ti_x single crystals is presented by means of ac and dc susceptibility and high-field magnetization measurements. A FOMP-like transition has been observed at low temperatures along the [001] direction for compounds with x = 0.85, 1.0, and 1.3. The transition critical field at 5 K decreases with increasing Ti content. A SRT has been also observed, in which the EMD changes from lying on the basal plane at low temperatures to be parallel to the caxis at high temperatures. $T_{\rm sr}$ decreases dramatically with increasing Ti content and is very sensitive to an external applied magnetic field. This result helps to clarify the confusion about the magnetic structures occurring in the RFe₁₁Ti compounds at different temperatures, as well as about the nature of the field-induced magnetic transitions. The magnetic behavior has been analyzed in a wide temperature range using a two-sublattice approximation for the magnetic structure. Within this approximation the Fe sublattice contribution to the free energy has been considered phenomenologically, whereas a single-ion CEF model has been used to describe the R sublattice contribution. The parameters B_2^0 , B_4^0 , B_6^0 , B_4^0 , and B_6^4 , describing the crystal-field interaction in TbFe_{12-x}Ti_x compounds, have been determined. The calculated magnetic behavior shows a good agreement with the experimental data. The fact that our model fulfils the strict conditions imposed by the existence of the SR- and FOMP-

like transitions confirms the reliability of the model and of the obtained CEF parameters sets.

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